LV0229XA

Front Monitor OE-IC, for Optical Pickups

ON Semiconductor®

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Overview

The LV0229XA is a front monitor optoelectronic IC for optical pickups that has a built-in photo diode compatible with three waveforms. LV0229XA is small size and type CSP packages.

Function

- Pin photodiode compatible with three wavelengths incorporated.
- Gain adjustment (-5dB to +5dB in 256 steps) through serial communication.
- Amplifier to amplify differential output.
- Photodiode compatible with three wavelengths incorporated, high-speed process employed.
- Compact, thin CSP package employed.
- Use AR coated glass for three-wavelength (One side).

Typical Applications

- Blu-ray Disk Drive for PC
- Blu-ray recorder
- Blu-ray player

ODCSP8 (1.35 x 1.23)

Specifications

Absolute Maximum Ratings at Ta = 25°C   (Note1)

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V_{CC}		6	V
Allowable power dissipation	Pd	substrate (Note2), Ta = 75°C	105	mW
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-40 to +100	°C

1. Stresses exceeding those listed in the Maximum Rating table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
2. Glass epoxy both-side substrate 55mm × 45mm × 1mm, Copper foil area (head: about 85%   tail: about 70%).

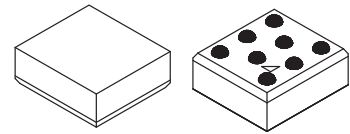### Recommended Operating Conditions at Ta = 25°C   (Note3)

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Operating supply voltage	V_{CC}		4.5	5	5.5	V
Output load capacitance	Co		12	20	33	pF
Output load resistance	Zo		3			kΩ

3. Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

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Electrical and Optical Characteristics at Ta = 25°C, V_{CC} = 5V, R_L = 6kΩ, C_L = 20pF   (Note4)

Parameter	Symbol	Conditions	IV Gain	Ratings min	Ratings typ	Ratings max	Unit
Current dissipation	I_{CC}			9	14	19	mA
Sleep current	Islp				0.2	0.5	mA
Output voltage when shielded	Vc	At shielding		1.85	2	2.15	V
Output offset voltage	Vofs	At shielding, voltage between VOP-VON		-30	0	30	mV
Temperature dependence of offset voltage (Note5)	Vofs	Ta = -10 to +75°C		-60	0	60	μV/°C
Optical output voltage (Note5) Voltage between VOP-VON	VLC	λ = 780nm, G = 0dB	Low	1.93	2.41	2.90	mV/μW
	VH1C		Middle	4.58	5.73	6.87	
	VH2C		High	10.86	13.58	16.29	
	VLD	λ = 650nm, G = 0dB	Low	2.03	2.54	3.05	
	VH1D		Middle	4.82	6.02	7.23	
	VH2D		High	11.42	14.28	17.13	
	VLB	λ = 405nm, G = 0dB	Low	1.27	1.59	1.90	
	VH1B		Middle	3.01	3.76	4.52	
	VH2B		High	7.14	8.92	10.71	
Light output voltage adjustment range (Note5)	G	G = 0dB reference, absolute value of adjustment width		4.5	5	5.5	dB
Output saturation voltage (Note5)	VoD	Voltage between VOP-VON		2000			mV
Frequency characteristics (Note5,6)	FcC	-3dB (1MHz reference), λ = 780nm Light input = 40μW (DC) + 20μW (AC)		40	60		MHz
	FcD1	-3dB (1MHz reference), λ = 650nm Light input = 40μW (DC) + 20μW (AC)	Low Middle	60	85		
	FcD2	-3dB (1MHz reference), λ = 650nm Light input = 40μW (DC) + 20μW (AC)	High	50	70		
	FcB1	-3dB (1MHz reference), λ = 405nm Light input = 40μW (DC) + 20μW (AC)	Low Middle	60	85		
	FcB2	-3dB (1MHz reference), λ = 405nm Light input = 40μW (DC) + 20μW (AC)	High	50	70		
Settling time (Note5)	Tset				10	15	ns
Response time (Note5)	Tr, Tf	Vo = 0.9Vp-p, output level 10 to 90% fc = 10MHz, duty = 50%			4	10	ns
Linearity (Note5)	Lin	At output voltage 0.5V and 1.0V (Between VOP-VON)		-1	0	1	%
Light-output voltage temperature dependence Voltage between VOP-VON (Note5,7)	TC	λ = 780nm, 25°C reference		6	9	12	%
	TD	λ = 650nm, 25°C reference		-3	0	3	%
	TB	λ = 405nm, 25°C reference		-2	1	4	%

4. Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
5. The design reference value.
6. The frequency characteristics when VOP and VON are applied individually.
   The frequency characteristics are for the output voltage adjustment range is -5 to +5dB.
7. The temperature dependence for the case of High / Middle / Low gain and for the case when the temperature is 25 to 75°C for the output voltage adjustment range of -5 to +5dB.

[Expression of output voltage]

$$Vn = (\text{sensitivity} / 1.78) \times 5221 / (5221 - 14 \times \text{GCAstep}) \times \text{light intensity (μW)}$$
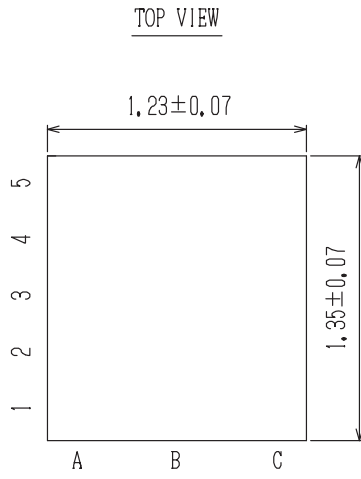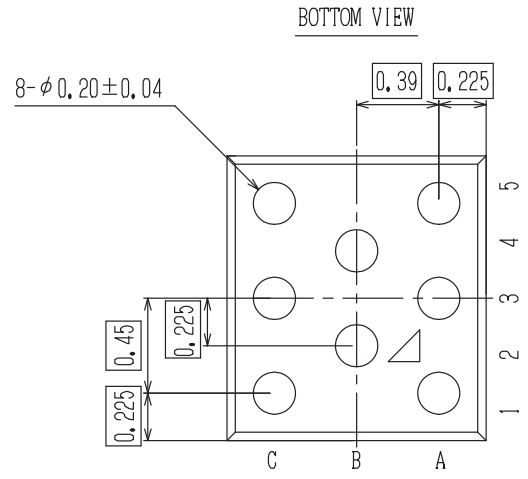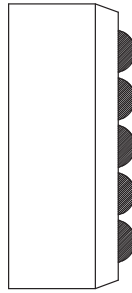
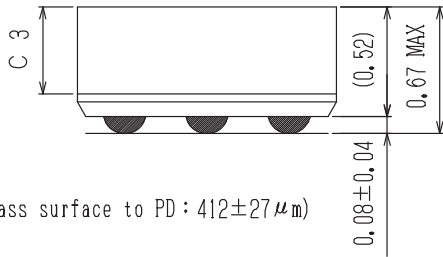# LV0229XA

Package Dimensions

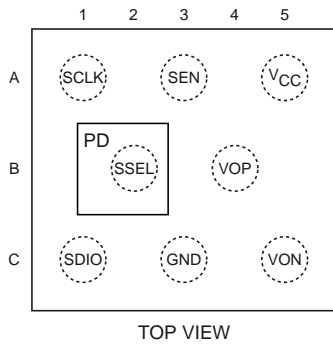unit : mm

ODCSP8 1.35x1.23
CASE 570AR
ISSUE O

TOP VIEW

1.23±0.07

5 4 3 2 1

1.35±0.07

A   B   C

SIDE VIEW

SIDE VIEW

C 3

(0.52)

0.67 MAX

0.08±0.04

C 3 = (Glass surface to PD : 412±27μm)

BOTTOM VIEW

8-φ0.20±0.04

0.39   0.225

5 4 3 2 1

0.45

0.225

0.225

C   B   A

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Pin Assignment

TOP VIEW

Pin No.	Pin name	Function
A1	SCLK	Serial communication Clock pin
A3	SEN	Serial communication Enable pin
A5	V_{CC}	Power supply voltage pin
B2	SSEL	Register selection pin
		SSEL = Low : Address 00 to 0Fh used
		SSEL = High : Address 10 to 1Fh used
		SSEL = Open : Address 70 to 7Fh used
B4	VOP	Positive side output pin
C1	SDIO	Serial communication Data pin
C3	GND	GND pin
C5	VON	Negative side output pin

PD assignment
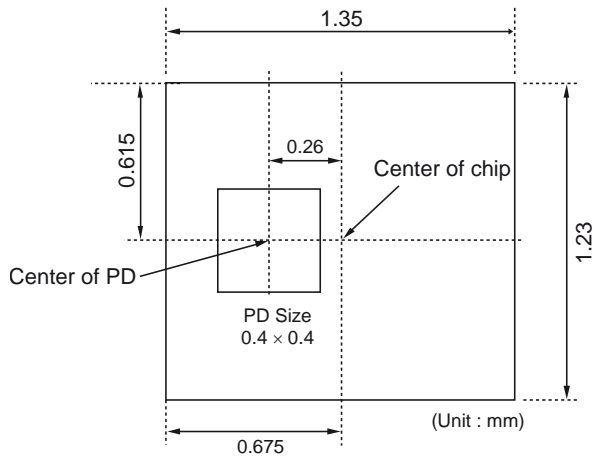
*PD size for reference to be used for design

(Unit : mm)

Block diagram and Test circuit diagram
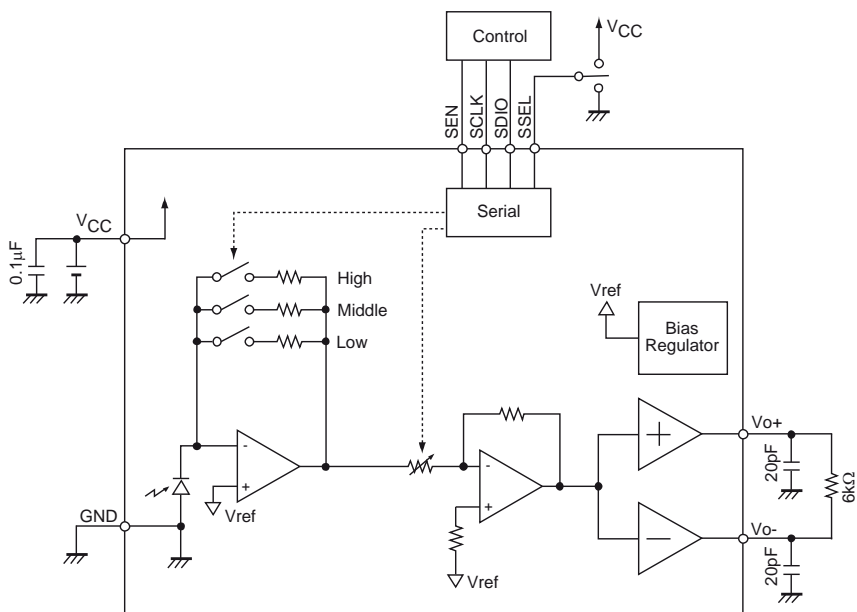
* Please place decoupling capacitors within 3mm from pin

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Resister table

Enable selection of the register group from the SSEL pin.

SSEL = Low

	Address	7	6	5	4	3	2	1	0
Name		POWER		IV GAIN SEL					
Default	00h	00		00		0	0	0	0
Value		11: Power on 00/01/10: Sleep		00/01: High 10: Middle 11: Low					
Name	01h	GAIN							
Default		1	1	1	1	1	1	1	1
Value		00000000 to 11111111							
Name	0Eh	TEST1 (*1)							

SSEL = High

	Address	7	6	5	4	3	2	1	0
Name		POWER		IV GAIN SEL					
Default	10h	00		00		0	0	0	0
Value		11: Power on 00/01/10: Sleep		00/01: High 10: Middle 11: Low					
Name	11h	GAIN							
Default		1	1	1	1	1	1	1	1
Value		00000000 to 11111111							
Name	1Eh	TEST1 (*1)							

SSEL = Open

	Address	7	6	5	4	3	2	1	0
Name		POWER		IV GAIN SEL					
Default	70h	00		00		0	0	0	0
Value		11: Power on 00/01/10: Sleep		00/01: High 10: Middle 11: Low					
Name	71h	GAIN							
Default		1	1	1	1	1	1	1	1
Value		00000000 to 11111111							
Name	7Eh	TEST1 (*1)							

*1 TEST1 are either the time when power is applied or "00000000" is set. Do not attempt to change "00000000" during operation.
"00000000" is returned when reading is made.

*2 No problem in terms of operation occurs even when writing is made to the address 02h to 0Dh & 0Fh, 12h to 1Dh & 1Fh and 72h to 7Dh & 7Fh.
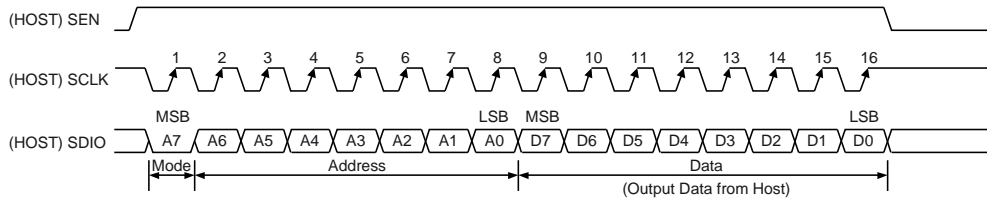"00000000" is returned when this address is read.

*3 When I performed address reading except the register group set by an SSEL terminal, I keep Hi-Z without paying a value.
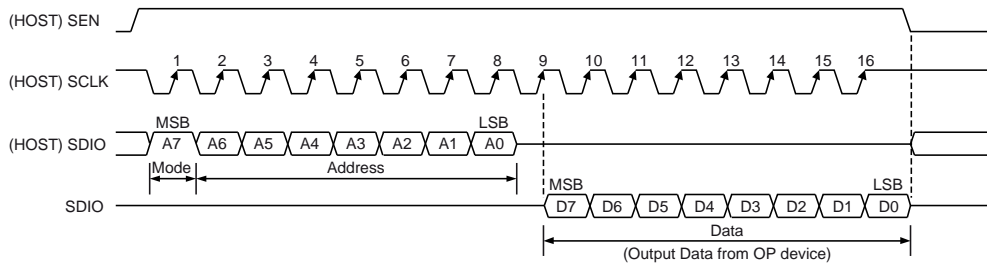
Serial protocol
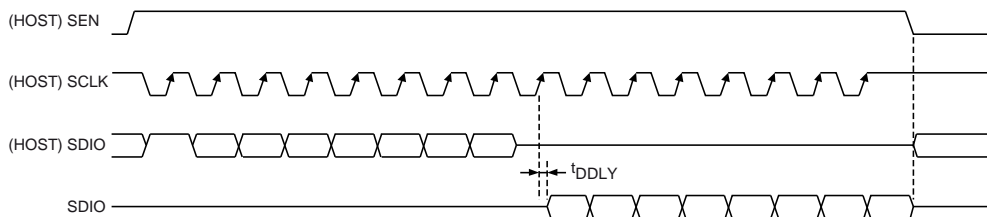
WRITE timing chart

READ timing chart

SDIO pin load / C_L = 20pF. The table below shows the design reference value.

Parameter	Symbol	Min.	Typ.	Max.	Unit
SCL clock frequency Write	f_{SCL}	0		10	MHz
SCL clock frequency Read	f_{SCL}	0		4	MHz
SDIO data setup time	t_{DSU}	50			ns
SDIO data hold time	t_{DHO}	50			ns
SDIO output delay	t_{DDLY}		10	80	ns
SEN "H" period	t_{ENH}	1.6			μs
SEN "L" period	t_{ENL}	200			ns
SCL rise time after SEN rise	t_{STA}	60			ns
SEN fall time after final SCL rise	t_{STO}	100			ns
Serial input "H" voltage	V_{IH}	2.4		V_{CC}	V
Serial input "L" voltage	V_{IL}			0.6	V
SDIO output "H" voltage	V_{OH}	2.5	2.9	3.3	V
SDIO output "L" voltage	V_{OL}	0	0.3	0.8	V

WRITE
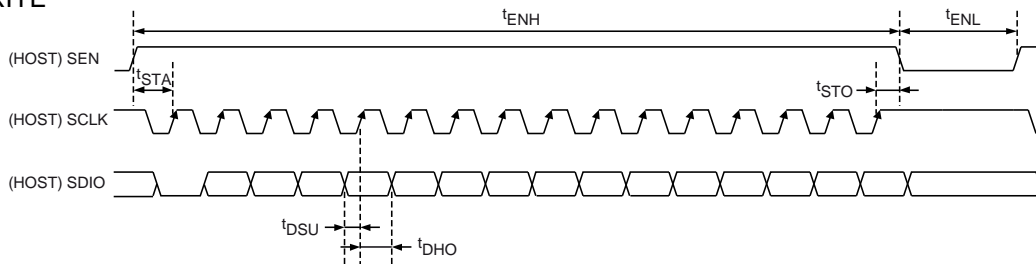
READ

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Pin Description

Pin	Type	Equivalent circuit diagram
SDIO	Input Output	3V 3V, 125 Ω, 125 Ω, 100kΩ
VOP VON	Output	20Ω
SCLK SEN	Input	3V, 100kΩ
SSEL	Input	800kΩ, 200kΩ, 5kΩ, 200kΩ

Write timing chart

(HOST) SEN

(HOST) SCLK 1 2 3 4 5 6 7 8 9 10 11 12 13 14 15 16

(HOST) SDIO MSB A7 A6 A5 A4 A3 A2 A1 A0 | LSB MSB D7 D6 D5 D4 D3 D2 D1 D0 LSB

Mode | Address | Data (Output Data from Host)

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